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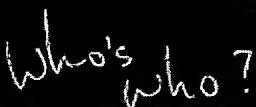
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   ...and technology of compound **semiconductor** OMVPE. VCSEL heterostructure...suggests, are a class of **semiconductor** laser in which an active...AlGaAs/AlGaAs quarter-wave **mirror** periods, (c) a one-wave optical...and low-refractive-index **semiconductor** layers. By spacing the multiple...
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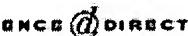
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Eric Cassan, *Journal of Applied Physics,* Jun 2000
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